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This single positive-edge-triggered D-type flip-flop is

breakthrough in IC packaging concepts, using the die

A low level at the preset (PRE) or clear (CLR) input

sets or resets the outputs, regardless of the levels of

the other inputs. When PRE and CLR are inactive (high), data at the data (D) input meeting the setup

time requirements is transferred to the outputs on the

positive-going edge of the clock pulse. Clock

triggering occurs at a voltage level and is not related

directly to the rise time of the clock pulse. Following

the hold-time interval, data at the D input can be

This device is fully specified for partial-power-down

applications using  $I_{\text{off}}$  . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow

changed without affecting the levels at the outputs.

through the device when it is powered down.

Ω

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package technology is a major

designed for 1.65-V to 5.5-V V<sub>CC</sub> operation.

# SINGLE POSITIVE-EDGE-TRIGGERED D-TYPE FLIP-FLOP WITH CLEAR AND PRESET

Check for Samples: SN74LVC2G74

DESCRIPTION

NanoFree™

as the package.

### **FEATURES**

- Available in the Texas Instruments NanoFree<sup>™</sup> Package
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V
- Max t<sub>pd</sub> of 5.9 ns at 3.3 V
- Low Power Consumption, 10-µA Max I<sub>CC</sub>
- ±24-mA Output Drive at 3.3 V
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- I<sub>off</sub> Supports Live Insertion, Partial Power Down Mode, and Back Drive Protection
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22

CLK [

DΓ

 $\overline{O}$ 

GND [

- 2000-V Human-Body Model (A114-A)
- 200-V Machine Model (A115-A)

3

Δ

See mechanical drawings for dimensions.

1000-V Charged-Device Model (C101)

#### DCT PACKAGE (TOP VIEW) 8 $\Box V_{cc}$ 1 PRF 2 7

6

5

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DCU PACKAGE CL

GND 🗌

	(10		
кШ	1	8	⊥ V <sub>cc</sub>
DШ	2	7	<u> </u>
<b>Q</b> □	3	6	

4

### **YZP PACKAGE** (BOTTOM VIEW)

GND	O4 50	Q
Q	O36O	CLR
D	0270	
CLK	O1 8O	$V_{\rm CC}$

 $\overline{\Lambda}\overline{\Lambda}$ 

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.

# SN74LVC2G74



### SCES203N-APRIL 1999-REVISED JULY 2013

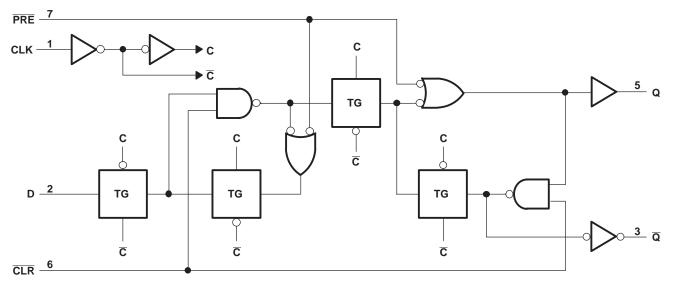
This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

FU	JN	СТ	10	Ν	TA	B	LE	

	INP	UTS		OUTI	PUTS
PRE	CLR	CLK	D	Q	Q
L	Н	Х	Х	Н	L
Н	L	Х	Х	L	Н
L	L	Х	Х	H <sup>(1)</sup>	H <sup>(1)</sup>
н	н	↑	Н	н	L
н	н	<b>↑</b>	L	L	н
Н	Н	L	Х	Q <sub>0</sub>	

(1) This configuration is nonstable; that is, it does not persist when PRE or CLR returns to its inactive (high) level.



### LOGIC DIAGRAM (POSITIVE LOGIC)



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### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	6.5	V
VI	Input voltage range <sup>(2)</sup>		-0.5	6.5	V
Vo	Voltage range applied to any output in the	he high-impedance or power-off state <sup>(2)</sup>	-0.5	6.5	V
Vo	Voltage range applied to any output in the	he high or low state <sup>(2) (3)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>0</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through V <sub>CC</sub> or GND	)		±100	mA
		DCT package		220	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DCU package		227	°C/W
		YZP package		102	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(3) The value of  $V_{CC}$  is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.



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### **RECOMMENDED OPERATING CONDITIONS**<sup>(1)</sup>

			MIN	MAX	UNIT
V	Supply voltoge	Operating	1.65	5.5	V
V <sub>CC</sub>	Supply voltage	Data retention only	1.5		V
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>		
V	High-level input voltage	$V_{CC}$ = 2.3 V to 2.7 V	1.7		V
VIH	High-level linput voltage	$V_{CC} = 3 V$ to 3.6 V	2		v
		$V_{CC}$ = 4.5 V to 5.5 V	$0.7 \times V_{CC}$		
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	
V	Low lovel input veltage	$V_{CC}$ = 2.3 V to 2.7 V		0.7	V
V <sub>IL</sub>	Low-level input voltage	$V_{CC} = 3 V$ to 3.6 V		0.8	v
		$V_{CC}$ = 4.5 V to 5.5 V		$0.3 \times V_{CC}$	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65 V		-4	
		$V_{CC} = 2.3 V$		-8	
I <sub>OH</sub>	High-level output current	$V_{CC} = 3 V$		-16	mA
		V <sub>CC</sub> = 3 V		-24	
		V <sub>CC</sub> = 4.5 V		-32	
		V <sub>CC</sub> = 1.65 V		4	
		V <sub>CC</sub> = 2.3 V		8	
l <sub>OL</sub>	Low-level output current	$V_{CC} = 3 V$		16	mA
		V <sub>CC</sub> = 3 V		24	
		V <sub>CC</sub> = 4.5 V		32	
		$V_{CC}$ = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V
		$V_{CC} = 5 V \pm 0.5 V$		5	
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

					-40°C	to 85°C	–40°C	to 125°C	
					-40 C	10 05 0	Recom	nmended	
P	ARAMETER	TEST CO	ONDITIONS	V <sub>cc</sub>		LVC2G74	SN74L	VC2G74	UNIT
					MIN	TYP <sup>(1</sup> ) MAX	MIN	TYP MA	x
		I <sub>OH</sub> = −100 μA		1.65 V to 5.5 V	V <sub>CC</sub> - 0.1		V <sub>CC</sub> - 0.1		
		$I_{OH} = -4 \text{ mA}$		1.65 V	1.2		1.2		
V <sub>OH</sub>		I <sub>OH</sub> = -8 mA		2.3 V	1.9		1.85		V
0.1.		I <sub>OH</sub> = -16 mA		3 V	2.4		2.4		
		I <sub>OH</sub> = -24 mA		3 V	2.3		2.3		
		I <sub>OH</sub> = -32 mA		4.5 V	3.8		3.8		
		I <sub>OL</sub> = 100 μA		1.65 V to 5.5 V		0.1		C	.1
		I <sub>OL</sub> = 4 mA		1.65 V		0.45		0.4	15
V <sub>OL</sub>		I <sub>OL</sub> = 8 mA		2.3 V		0.3		C	.3 V
02		I <sub>OL</sub> = 16 mA		3 V		0.4		C	.4
		I <sub>OL</sub> = 24 mA		3 V		0.55		0.	55
		I <sub>OL</sub> = 32 mA		4.5 V		0.55		0.	55
I,	Data or control inputs	$V_1 = 5.5 V \text{ or GND}$		0 to 5.5 V		±5		:	⊧5 μA
I <sub>off</sub>		$V_{\rm I}$ or $V_{\rm O}$ = 5.5 V		0		±10		±	0 μA
I <sub>CC</sub>		$V_{I} = 5.5 V \text{ or GND},$	I <sub>O</sub> = 0	1.65 V to 5.5 V		10			0 μΑ
ΔI <sub>CC</sub>		One input at $V_{CC} - 0.6$ V,	Other inputs at $V_{CC}$ or GND	3 V to 5.5 V		500		5	00 μA
Ci		$V_{I} = V_{CC}$ or GND		3.3 V		5		5	pF

(1) All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

### TIMING REQUIREMENTS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

						SN74LV	/C2G74				
Devementer	From	То				–40°C t	o 85°C				UNIT
Parameter	From	10	V <sub>CC</sub> = 1.8V	±0.15V	V <sub>CC</sub> = 2.5V	/ ±0.2V	V <sub>CC</sub> = 3.3V	/ ±0.3V	$V_{CC} = 5V$	±0.5V	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>				80		175		175		200	MHz
+	CLF	<	6.2		2.7		2.7		2		20
t <sub>w</sub>	PRE or C	LR low	6.2		2.7		2.7		2		ns
	Data	а	2.9		1.7		1.3		1.1		
t <sub>su</sub>	PRE or CLF	R inactive	1.9		1.4		1.2		1		ns
t <sub>h</sub>			0		0.3		1.2		0.5		ns

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### TIMING REQUIREMENTS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

						SN74LV	C2G74				
Devementer	From	Та				–40°C to	o 125°C				
Parameter	From	То	V <sub>CC</sub> = 1.8V	±0.15V	V <sub>CC</sub> = 2.5V	′ ±0.2V	V <sub>CC</sub> = 3.3V	±0.3V	$V_{CC} = 5V$	±0.5V	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>				80		120		120		140	MHz
	CLł	<	6.2		3.5		3.5		3.3		
L <sub>W</sub>	PRE or C	LR low	6.2		3.5		3.5		3.3		ns
	Dat	а	2.9		23		1.9		1.7		
t <sub>su</sub>	PRE or CLF	R inactive	1.9		2		1.8		1.6		ns
t <sub>h</sub>			0		0.3		0.5		0.5		ns

### SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

	To -44   V_{CC} = 1.8V ±0.15V V_{CC} = 2.5V ±0.2   MIN MAX MIN N   CLK Q 4.8 13.4 2.2   Q 6 14.4 3	SN74LV	4LVC2G74								
Parameter	From	Та				–40°C t	o 85°C				UNIT
Parameter	From	10	V <sub>CC</sub> = 1.8V	±0.15V	V <sub>CC</sub> = 2.5V	/ ±0.2V	V <sub>CC</sub> = 3.3V	′ ±0.3V	$V_{CC} = 5V$	±0.5V	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>			80		175		175		200		MHz
	<u>CLK</u>	Q	4.8	13.4	2.2	7.1	2.2	5.9	1.4	4.1	
t <sub>pd</sub>	CLK	Q	6	14.4	3	7.7	2.6	6.2	1.6	4.4	ns
	PRE or CLR low	Q or Q	4.4	12.9	2.3	7	1.7	5.9	1.6	4.1	

### SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

t <sub>pd</sub>					SN74LV	/C2G74						
Devementer	From	Те		–40°C to 125°C								
Parameter	From	10	V <sub>CC</sub> = 1.8V	±0.15V	V <sub>CC</sub> = 2.5V	/ ±0.2V	V <sub>CC</sub> = 3.3V	′ ±0.3V	$V_{CC} = 5V$	±0.5V	UNIT	
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
f <sub>max</sub>			80		120		120		140		MHz	
	CLK	Q	4.8	14.4	2.2	8.1	2.2	6.9	1.4	5.1		
t <sub>pd</sub>	CLK	Q	6	16	3	9.7	2.6	7.2	1.6	5.4	ns	
	PRE or CLR low	Q or Q	4.4	14.9	2.3	9.5	1.7	7.9	1.6	6.1		

## **OPERATING CHARACTERISTICS**

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	$V_{CC} = 2.5 V$	$V_{CC} = 3.3 V$	$V_{CC} = 5 V$	UNIT
	FARAIMETER	TEST CONDITIONS	TYP	TYP	TYP	TYP	UNIT
$C_{\text{pd}}$	Power dissipation capacitance	f = 10 MHz	35	35	37	40	pF

# SN74LVC2G74

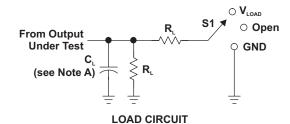
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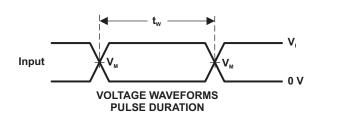
#### SCES203N-APRIL 1999-REVISED JULY 2013

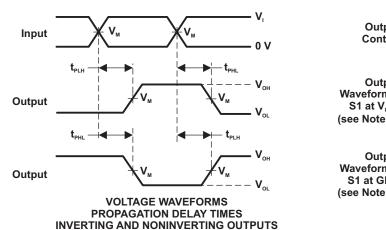
### PARAMETER MEASUREMENT INFORMATION

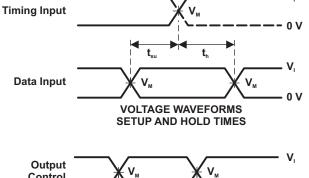


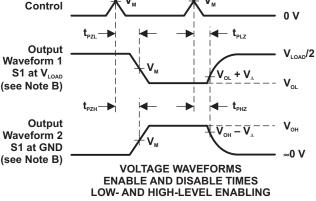
TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$V_{load}$
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

	INF	PUTS	N	V	•		V	
V <sub>cc</sub>	V	t,/t,	V <sub>M</sub>	$V_{load}$	C	R		
1.8 V ± 0.15 V	V <sub>cc</sub>	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	30 pF	<b>1 k</b> Ω	0.15 V	
$2.5 V \pm 0.2 V$	$V_{cc}$	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	30 pF	<b>500</b> Ω	0.15 V	
3.3 V ± 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V	
$5 V \pm 0.5 V$	$V_{cc}$	≤2.5 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	50 pF	<b>500</b> Ω	0.3 V	









NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>0</sub> = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{\mbox{\tiny PZL}}$  and  $t_{\mbox{\tiny PZH}}$  are the same as  $t_{\mbox{\tiny en}}.$
- G.  $t_{\mbox{\tiny PLH}}$  and  $t_{\mbox{\tiny PHL}}$  are the same as  $t_{\mbox{\tiny pd}}$
- H. All parameters and waveforms are not applicable to all devices.

### Figure 1. Load Circuit and Voltage Waveforms

# **REVISION HISTORY**

C	Changes from Revision M (February 2007) to Revision N							
•	Changed I <sub>off</sub> description in FEATURES.	1						
•	Added parameter values for –40 to 125°C temperature ratings.	5						
•	Changed TIMING REQUIREMENTS table.	5						
•	Added TIMING REQUIREMENTS table.	6						
•	Changed SWITCHING CHARACTERISTICS table.	6						

•	Changed SWITCHING CHARACTERISTICS table.	6
•	Added SWITCHING CHARACTERISTICS table.	6

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### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC2G74DCTR	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C74 Z	Samples
SN74LVC2G74DCTRE4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C74 Z	Samples
SN74LVC2G74DCTRG4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C74 Z	Samples
SN74LVC2G74DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-40 to 125	(74 ~ C74Q ~ C74R) CZ	Samples
SN74LVC2G74DCURE4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C74R	Samples
SN74LVC2G74DCURG4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C74R	Samples
SN74LVC2G74DCUT	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-40 to 125	(C74Q ~ C74R)	Samples
SN74LVC2G74DCUTE4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C74Q ~ C74R)	Samples
SN74LVC2G74DCUTG4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C74Q ~ C74R)	Samples
SN74LVC2G74YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(CP7 ~ CPN)	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)



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<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN74LVC2G74 :

Automotive: SN74LVC2G74-Q1

Enhanced Product: SN74LVC2G74-EP

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

# PACKAGE MATERIALS INFORMATION

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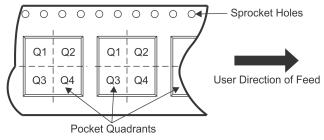
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### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2G74DCUR	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC2G74DCURG4	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC2G74YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

8-Nov-2013



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC2G74DCUR	US8	DCU	8	3000	202.0	201.0	28.0
SN74LVC2G74DCURG4	US8	DCU	8	3000	202.0	201.0	28.0
SN74LVC2G74YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0

# **MECHANICAL DATA**

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

### DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



DCT (R-PDSO-G8) PLASTIC SMALL OUTLINE Example Board Layout Example Stencil Design (Note C,E) (Note D) - 6x0,65 - 6x0,65 8x0,25-8x1,55 3,40 3,40 Non Solder Mask Defined Pad Example Pad Geometry -0,30 (Note C) 1,60 Example -0,07 Non-solder Mask Opening All Around (Note E) 4212201/A 10/11

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.



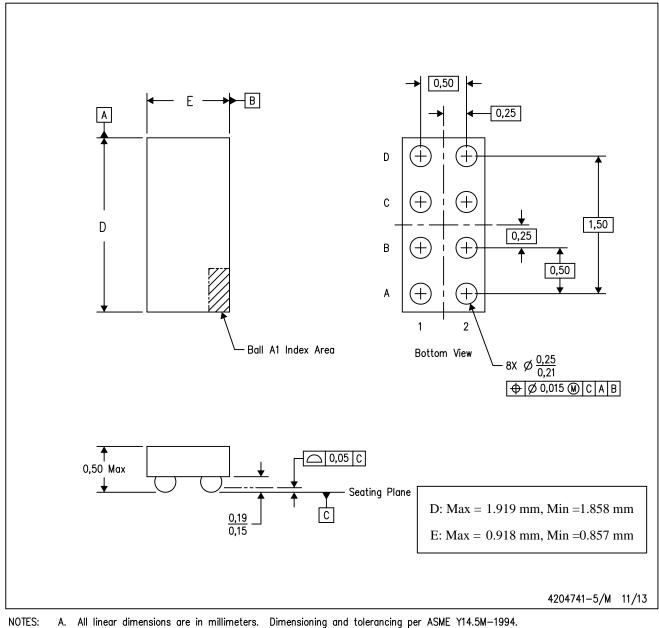


- NOTES: A. All linear dimensions are in millimeters. В. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- A. All linear dimensions are in millimeters. Dimension B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.



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